



Cite this: *Nanoscale*, 2023, **15**, 387

Correction: Redox-controlled conductance of polyoxometalate molecular junctions

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DOI: 10.1039/d2nr90231a
[rsc.li/nanoscale](https://doi.org/10.1039/d2nr90231a)

Correction for 'Redox-controlled conductance of polyoxometalate molecular junctions' by Cécile Huez *et al.*, *Nanoscale*, 2022, **14**, 13790–13800, <https://doi.org/10.1039/D2NR03457C>.

In this paper there is a typographic error in eqn (1) in the published version. The correct equation reads:

$$I(V) = N \frac{8e}{h} \frac{\Gamma_1 \Gamma_2}{\Gamma_1 + \Gamma_2} \left[\arctan \left(\frac{\varepsilon_{0\text{-SEL}} + \frac{\Gamma_1}{\Gamma_1 + \Gamma_2} eV}{\Gamma_1 + \Gamma_2} \right) - \arctan \left(\frac{\varepsilon_{0\text{-SEL}} - \frac{\Gamma_2}{\Gamma_1 + \Gamma_2} eV}{\Gamma_1 + \Gamma_2} \right) \right] \quad (1)$$

The correct equation was implemented to fit the experimental datasets during the course of the work, thus this typographic error does not impact the results.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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